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Impurity effect as a probe of the paring symmetry in $\mathrm{BiS_2}$ based superconductors

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The impurity effects are studied for the $\mathrm{BiS_2}$- layered superconductors based on a two orbital model with the Bogoliubov-de-Gennes technique. The superconducting critical temperature ($\mathrm{T_c}$) as a function of the impurity concentration is calculated. Significant reduction of $\mathrm{T_c}$ is found for spin singlet nearest-neighboring paring d-wave state and the spin triplet next-nearest-neighboring (NNN) paring p-wave state, while no depression of $\mathrm{T_c}$ for isotropic s-wave state. The single impurity effects for various paring states are also explored. The impurity resonance peak in the local density of states spectrum is found only for the d-wave state. For the spin triplet NNN paring p-wave state, two in-gap peaks occur in the case of positive impurity potential; and a single in-gap peak is found for the negative impurity potential, which shifts towards to lower energy with decreasing the potential strength. These results can be used to detect the paring symmetry of the $\mathrm{BiS_2}$- based superconductors.

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Superconductors with layered crystal structures such as cuprates[1], $\mathrm{Sr_2RuO_4}$[2], $\mathrm{MgB_2}$[3], $\mathrm{Na_xCo_2O_2}$[4], and iron pnictides[5] have generated enormous research interest. The low dimensionality can affect the electronic structure and can realize high transition temperatures ($\mathrm{T_c}$) and/or unconventional superconductivity mechanisms. Quite recently, superconductivity has been observed in the $\mathrm{BiS_2}$- based compounds[6], such as $\mathrm{Bi_4O_4S_3}$[6], $\mathrm{LaO_{1-x}F_xBiS_2}$[7], $\mathrm{NdO_{1-x}F_xBiS_2}$[8], $\mathrm{CeO_{1-x}F_xBiS_2}$[9], and $\mathrm{PrO_{0.5}F_{0.5}BiS_2}$[10], where the $\mathrm{BiS_2}$- layer is a basic unit. Soon after that, considerable efforts have been paid on the investigation of the physical properties in this system[11–25]. The discovery of the newly basic superconducting (SC) layers may open new fields in physics and chemistry of low-dimensional superconductors.

The $\mathrm{BiS_2}$- based materials compose of a stacking of $\mathrm{BiS_2}$- SC layers and the spacer layers, which resembles those of high-$\mathrm{T_c}$ cuprates and the Fe-based superconductors. From the first principles band structure calculations[6,11], it predicts that the dominating bands for the electron conduction as well as for the superconductivity are derived from the Bi $6p_x$ and $6p_y$ orbits. According to the Hall effect and the magnetoresistance measurements[12], an exotic multi-band features are found in the $\mathrm{Bi_4O_4S_3}$ compounds and the SC pairing occurs in the one dimensional chains. Electrical resistivity measurements under pressure[16] reveal that $\mathrm{Bi_4O_4S_3}$ and $\mathrm{LaO_{1-x}F_xBiS_2}$ have different T_c versus pressure behavior, and the Fermi surface of $\mathrm{LaO_{1-x}F_xBiS_2}$ may be located in the vicinity of some band edges leading to instability for superconductivity. In the $\mathrm{CeO_{1-x}F_xBiS_2}$ system[9], it is found that the parent phase is a bad metal, instead of a band insulator in the case of $\mathrm{Bi_4O_4S_3}$ compounds[6]. By doping electrons into the system, superconductivity appears together with an insulating normal state[9], which is clearly different from the cuprates and the iron pnictides.

The most fundamental issue is the superconductivity mechanism in this $\mathrm{BiS_2}$- based compound, which is still unclear. It is predicted that the electron-phonon coupling constant is as large as $\lambda = 0.85$, which emphasizes that $\mathrm{LaO_{1-x}F_xBiS_2}$ is a strongly coupled electron-phonon superconductor[18,19]. While, a good nesting of the Fermi surface at wave vector $\mathbf{k} = (\pi, \pi, 0)$ has been found[11,18]. It is also proposed that the SC pairing is strong and exceeds the limit of the phonon mediated picture[12]. Moreover, the anharmonic model calculation shows that the vicinity of the charge-density-wave (CDW) instability is essential for the superconductivity[18], which is reminiscent to iron pnictides whose proximity to spin-density-wave (SDW) is well established[5]. Thus, the spin fluctuation is also proposed to account for the SC pairing in this family[17].

Another puzzle is the SC paring symmetry of the $\mathrm{BiS_2}$-based superconductors. Based on the the first principles calculation[11], it is found that the Fermi level for the nominal composition is located in the vicinity of the topological change in the Fermi surface. This gives a possibility that the SC symmetry changes depending on the doping level, provided that the superconductivity originates from the electric correlation. Considering various many-body interactions, possible paring states are proposed, such as sign conserving/reversing s-wave and d-wave states[11,17]. Furthermore, the first principles calculation indicates the quasi-one-dimensional bands[11], which may leads to the spin-triplet pairing. In the $\mathrm{CeO_{1-x}F_xBiS_2}$ compounds, superconductivity and ferromagnetism (FM) is found to coexist[9], where FM may arise from the Ce moments. The coexistence of superconductivity and FM challenges the spin-singlet paring mechanism, which reminds us of the $\mathrm{Sr_2RuO_4}$ material where the short-range ferromagnetic spin fluctuations give rise to the triplet pairing with p-like symmetry[26].

The impurity effect is one of the most important tools for identifying the nature of the paring state and the microscopic properties, which has been successfully carried out in both conventional superconductors[27] and unconventional ones, such as cuprates[28] and iron pnictides[29–35]. In this paper, we will study theoretically the impurity effect in the $\mathrm{BiS_2}$- based materials and look into the pairing symmetry based on the two-orbital model from the first principles calculation[11] and the Bogoliubov-de-Gennes (BdG) equations. The impurity concentration dependence of the critical temperature is explored. Significant reduction of $\mathrm{T_c}$ is found for spin singlet nearest-neighboring (NN) paring d-wave state and the spin triplet next-nearest-neighboring (NNN) paring p-wave state, while no depression of $\mathrm{T_c}$ for isotropic s-wave state. The single impurity effects for various paring states are also calculated. The impurity resonance peak in the local density of states (LDOS) spectrum is found only for the d-wave state. The evolution of the resonance peak with the impurity strength is also calculated. For the spin triplet NNN paring p-wave state, two in-gap peaks occur in the case of positive impurity potential; and a single in-gap peak is found for the negative impurity potential, which shifts towards to lower energy with decreasing the potential strength. These results can be used to detect the paring symmetry of the $\mathrm{BiS_2}$- based superconductors.

The starting model Hamiltonian with the hopping elements, the pairing terms and the impurity part is expressed by

$$H = H_t + H_\Delta + H_{\mathrm{imp}}. \tag{1}$$

In the present work, we use the two orbital model with the hopping constants being from Ref. [11]. Thus, the hopping term H_t can be expressed by

$$H_t = -\sum_{i\mu j\nu\sigma}(t_{i\mu j\nu} c^\dagger_{i\mu\sigma} c_{j\nu\sigma} + \mathrm{H.c.}) - t_0 \sum_{i\mu\sigma} c^\dagger_{i\mu\sigma} c_{i\mu\sigma}, \tag{2}$$

where i,j are the site indices and $\mu, \nu = 1, 2$ are the orbital indices. And t_0 is the chemical potential. Considering the possibilities of both spin singlet and triplet pairings, the paring term is written as

$$H_\Delta = \sum_{ij}[\Delta^\pm_{i\mu j\nu}(c^\dagger_{i\mu\uparrow} c^\dagger_{j\nu\downarrow} \pm c^\dagger_{i\mu\downarrow} c^\dagger_{j\nu\uparrow}) + \mathrm{H.c.}]. \tag{3}$$

Here, $\pm$ is for spin-triplet and singlet pairings, respectively, and the pairing potential $\Delta^\pm_{i\mu j\nu}$ is defined as $\Delta^\pm_{i\mu j\nu} = \frac{V_{i\mu j\nu}}{2}(\langle c_{i\mu\uparrow} c_{j\nu\downarrow}\rangle \pm \langle c_{i\mu\downarrow} c_{j\nu\uparrow}\rangle)$, where $V_{i\mu j\nu}$ is the SC interaction. And H_{imp} is the impurity part of the Hamiltonian, written as

$$H_{\mathrm{imp}} = \sum_{i_{\mathrm{m}}\mu\sigma} V_s c^\dagger_{i_{\mathrm{m}}\mu\sigma} c_{i_{\mathrm{m}}\mu\sigma}. \tag{4}$$

In this paper, both single- and multiple- impurity effects are studied, and only the intraorbital scattering by nonmagnetic impurities is considered.

Then, the Hamiltonian can be diagonalized by solving the BdG equations self-consistently,

$$\sum_j \sum_\nu \begin{pmatrix} H_{i\mu j\nu\sigma} & \Delta^\pm_{i\mu j\nu} \\ \mp\Delta^{\pm *}_{i\mu j\nu} & -H^*_{i\mu j\nu\bar{\sigma}} \end{pmatrix} \begin{pmatrix} u^n_{j\nu\sigma} \\ v^n_{j\nu\bar{\sigma}} \end{pmatrix} = E_n \begin{pmatrix} u^n_{i\mu\sigma} \\ v^n_{i\mu\bar{\sigma}} \end{pmatrix}, \tag{5}$$

where the Hamiltonian $H_{i\mu j\nu\sigma}$ is expressed by,

$$H_{i\mu j\nu\sigma} = -t_{i\mu j\nu} - t_0\delta_{ij}\delta_{\mu\nu} + \sum_{i_m} V_s \delta_{i,i_m}. \tag{6}$$

The SC order parameter $\Delta_{i\mu j\nu}$ and the local electron density $\langle n_{i\mu}\rangle$ are obtained self-consistently:

$$\Delta^\pm_{i\mu j\nu} = \frac{V_{i\mu j\nu}}{4}\sum_n (u^n_{i\mu\uparrow} v^{n*}_{j\nu\downarrow} \mp u^n_{j\nu\uparrow} v^{n*}_{i\mu\downarrow}) \tanh\left(\frac{E_n}{2k_B T}\right), \tag{7}$$

$$\langle n_{i\mu}\rangle = \sum_n |u^n_{i\mu\uparrow}|^2 f(E_n) + \sum_n |v^n_{i\mu\downarrow}|^2[1 - f(E_n)]. \tag{8}$$

Here $f(x)$ is the Fermi distribution function. The LDOS is expressed by

$$\rho_i(\omega) = \sum_{n\mu}[|u^n_{i\mu\sigma}|^2\delta(E_n - \omega) + |v^n_{i\mu\bar{\sigma}}|^2\delta(E_n + \omega)], \tag{9}$$

where the delta function $\delta(x)$ has been approximated by $\Gamma/\pi(x^2 + \Gamma^2)$ with the quasiparticle damping $\Gamma = 0.002$.

Following Ref.[17], we focus our studies on the optimal doped sample with $x = 0.56$ used throughout the present work. The paring strength is chosen the be $V_{i\mu j\nu} = 0.6$eV for all paring states. The numerical calculation is performed on a 24×24 lattice with the periodic boundary conditions. In this paper, the energy and length are measured in units of eV and the Bi-Bi distance a, respectively. To calculate the LDOS, a 80×80 supercell technique is used.

Based on our self-consistent calculation, various paring symmetries are obtained for the different paring states. For the spin singlet onsite paring, an isotropic s- wave state occurs. For the spin singlet NN paring, the paring symmetry is d- wave. To get the NN paring extended s-wave, we set $\Delta_{i+\hat{x}} = \Delta_{i+\hat{y}}$ in the previous result. For the spin singlet NNN paring, due to the anisotropic hopping in the $(\hat{x} + \hat{y})$ and $(-\hat{x} + \hat{y})$ directions, the gap consists both s- and d- wave components, i.e., the $\mathrm{s - d}$ wave in the p_x orbit and $\mathrm{s + d}$ wave in the p_y orbit. To obtain the one dimensional spin triplet p- wave state, the paring interaction is only considered in the $(\hat{x} + \hat{y})$ direction of the p_x orbit and in the $(-\hat{x} + \hat{y})$ direction of the p_y orbit.

We first study the multiple-impurity effect for various paring states. In this case, the impurities are randomly distributed in the 24×24 lattice and only the strong impurity potential $V_s = 10$eV is considered. The impurity concentration dependence of the reduced critical transition temperature T_c/T_{c0} is presented in Fig. 1, where T_{c0} is the critical transition temperature without any impurity. As seen, for the onsite paring s-wave state, the critical temperature T_c does not decrease with the

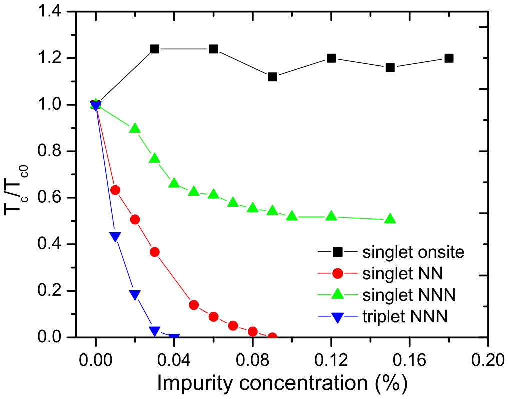

FIG. 1: (Color online) The impurity concentration dependence of the reduced critical transition temperature T_c/T_{c0} for various paring states, where T_{c0} is the critical transition temperature without any impurity.

increasing impurity concentration. While, it decreases with increasing impurity concentration for the other paring states, such as spin singlet NN paring, NNN paring, and spin triplet NNN paring states. For the spin singlet NNN paring state, the critical temperature decreases rapidly in the low impurity concentration region ($\leq 5\%$), then it almost saturates with further increasing the impurity concentration. For the spin singlet NN paring d-wave state and the spin triplet NNN paring p-wave state, the critical transition temperature decreases with the increasing impurity concentration monotonically. While, the reduction of the critical temperature in the p-wave state is faster than that in the d-wave state.

Generally, studying the nonmagnetic impurity effect on superconductors helps greatly to investigate the pairing symmetry. It is well known that superconductivity is robust against small concentrations of nonmagnetic impurities in conventional s-wave superconductors, according to the Anderson's theorem[36]. Since superconductivity is due to the instability of the Fermi surface to pairing of time-reversed quasiparticle states, any perturbation that does not lift the Kramers degeneracy of these states does not affect the mean-field SC transition temperature. While, a magnetic impurity, owing to the effect of breaking the time reversal symmetry, can break Cooper pairs easily. For instance, MgB_2 is a BCS-type supercondoctor with the electron-phonon coupling and its symmetry is a s-wave, revealed by enormous experiments[37], such as the isotope effect by the substitution of ^{11}B[38] and the observation of a coherent peak in the nuclear magnetic resonance (NMR) experiment[39]. Zn ions have a full d shell and are nominally nonmagnetic. Effect of Zn-substitution on the MgB_2 superconductor shows that the critical transition temperature T_c is almost unchanged with small Zn-concentration, while T_c is significantly suppressed by the substitution of magnetic ions[40]. These results are consistent with the Anderson's theorem. For the BiS_2- based superconductor, the density functional based calculations shows that this material may be a conventional s-wave superconductor with large electron-phonon coupling constant[18,19]. If this is the case, the critical transition temperature T_c should not be depressed by small concentration of non-magnetic impurities, as revealed by our numerical calculation presented in Fig. 1. Note that there is an enhancement of T_c by the nonmagnetic impurity substitution, which is perhaps due to the enhanced density of state near the Fermi level.

In contrast to the isotropic s-wave superconductors, nonmagnetic impurities are paring breakers in anisotropic superconductors, such as heavy fermion superconductors[41] and cuprats[42]. Based on the second Born approximation and the strong-coupling Eliashberg theory, impurity-induced T_c suppression in d-wave cuprate superconductors has been predicted[42]. Experimentally, Zn substitution for Cu in the high-T_c cuprates dramatically suppresses superconductivity. For instance, it has been shown that an impurity concentration of 2-3 at.% (per Cu) reduces T_c to half or less the value for unsubstituted systems over a wide region of hole doping level in Zn substituted $La_{2-x}Sr_xCuO_4$ and $YBa_2Cu_3O_{6+x}$[43–45]. In our self-consistent calculation, it is found that the paring symmetry is d-wave in the NN singlet paring states for BiS_2- compounds. The critical transition temperature T_c is suppressed significantly by small concentration of nonmagnetic impurities. This result is similar to that of high T_c cuprate superconductors, indicating the paring breaking effect in d-wave SC gap. While, in the NNN singlet paring state, T_c is suppressed quickly for small impurity concentration then saturates with further increasing impurities. According to our calculation, the SC gap has both s- and d- wave components. Hence, the suppression of T_c is the consequence of the paring break effect of the d-wave component in the SC gap. While, the saturation of T_c is due to the s-wave component.

In principle, nonmagnetic impurities are pair breakers for higher-orbital momentum states, such as p-wave state[28]. The reduction of T_c due to nonmagnetic impurity scattering in Sr_2RuO_4 compound with p-wave like symmetry has been calculated from the conventional Abrikosov-Goŕkov formula[26], which has been proved by the substitution of nonmagnetic impurity Ti^{4+} ions[46,47]. For the BiS_2- based superconductors, possible spin triplet p-wave paring state is proposed[11,17]. From our self-consistent calculation, the rapid depression of T_c by nonmagnetic impurity substitution can be tested experimentally.

We now turn to study the single- impurity effect in the LDOS spectra of various paring symmetries. The calculated results are presented in Fig. 2(a)-2(e). Shown in Fig. 2(a) is the LDOS spectra around a nonmagnetic impurity for the isotropic s- wave paring state. As can be seen, the LDOS spectrum in the bulk has a U-shaped

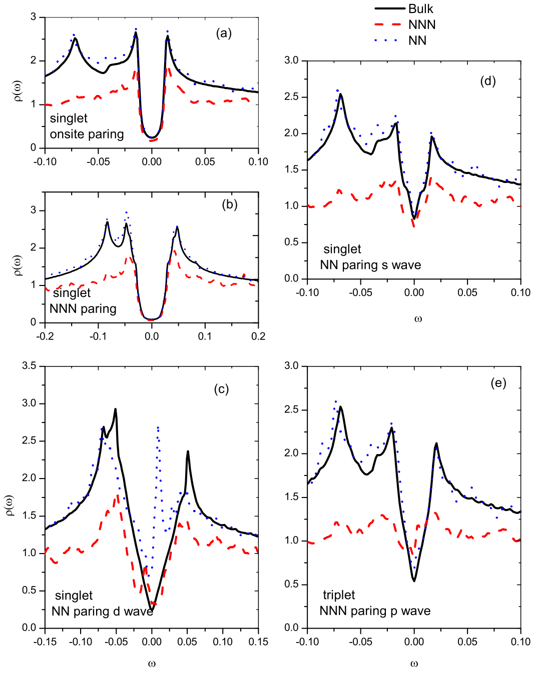

FIG. 2: (Color online) LDOS spectra around a nonmagnetic impurity at various paring states. The impurity strength is set to be $V_s = 10$eV. The solid (black) curves are the LDOS spectra in the bulk, the dotted (blue) curves are the LDOS spectra at the NN sites of the impurity, and the dashed (red) curves are the LDOS spectra at the NNN sites of the impurity. (a): Spin singlet of onsite paring state; (b): Spin singlet of NNN paring state; (c): Spin singlet of NN paring for d wave state; (d): Spin singlet of NN paring for extended s wave state; (e): Spin triplet of NNN paring for p wave state.

bottom, indicating a fully SC gap. Outside the gap, the van Hove singularity peak is clearly seen. At the NN site of the impurity, the LDOS spectrum is almost unchanged compared with that in the bulk, while at the NNN site of the impurity, the SC coherence peaks in the LDOS spectrum are depressed. From the above result, it is found that there is no impurity state in the isotropic s- wave paring state. In general, potential scattering impurities are not pair breaker in the s- wave case according to the Anderson theorem[28]. Presented in Fig. 1(b) is the LDOS spectra for the spin singlet NNN paring state. The results are similar to the case of the onsite paring state, i.e., the LDOS spectrum has a U-shaped bottom and no impurity state occurs inside the SC gap.

The LDOS spectra for the spin singlet NN paring d-wave state are shown in Fig. 2(c). It is found that the LDOS spectrum has a V-shaped bottom in the bulk, indicating the nodal characteristics. At the NN site of the impurity, there is a sharp resonance peak at $\omega_0 = 9$meV in the LDOS spectrum. At the NNN site of the impurity, there is also a weak in-gap peak at $\omega_0 = -9$meV. Note that, the SC coherence peaks are also depressed obviously by the impurity at the NNN site. The resonance peak inside the SC gap at the NN site of the impurity is a general feature in a d-wave superconductor, which has already been reported in cuprate superconductors both theoretically[28] and experimentally[48]. The LDOS spectra for the spin singlet NN paring s- wave state are presented in the Fig. 2(d). The LDOS spectrum in the bulk still has a V-shaped bottom. The LDOS spectrum at the NN site of the impurity is almost unchanged compared with that in the bulk. Similar to the spin singlet onsite and NNN paring states, there is no impurity state in this case. However, at the NNN site of the impurity, the SC coherence peaks are almost flattened, which is quite different from those in the previous cases.

The LDOS spectra for the spin triplet NNN paring p-wave state are shown in Fig. 2(e). As one can see, the LDOS spectrum in the bulk is also V-shaped with nodal characteristics. Previously, a fully nodeless SC gap was found in the $\mathrm{Sr_2RuO_4}$ superconductors from the scanning tunnelling microscopy experiments[49], which is quite different with our result. This is most due to its complex paring symmetry with out nodes at the Fermi surface, i.e., $\sin p_x + i\sin p_y$ wave or $\sin(p_x + p_y) + i\sin(-p_x + p_y)$ wave[50]. At the NN site of the impurity, there is a small in-gap peak at $\omega_0 = 3$meV in the spectrum. At the NNN site of the impurity, two in-gap peaks are found at $\omega_0 = \pm 3$meV, where the in-gap peak at the positive energy is much stronger than that at the negative energy. Moreover, the SC coherence peaks are almost flattened by the impurity, similar to that of the spin singlet NN paring s-wave state. From the above discussion, one can concludes that there are impurity resonance peaks only in the spin singlet NN paring d- wave state. The resonance peak is very sharp in the LDOS spectrum at the NN site. While, two in-gap peaks occur in the spectrum at the NNN site for the p- wave paring state and the SC coherence peaks are almost flattened by the impurity. These results can be used to detect the paring symmetry in the $\mathrm{BiS_2}$- based superconductors.

The potential strength response of the impurity states is also calculated. The impurity states at various potential strength for the d-wave paring state are presented in Fig. 3(a)-3(e). As seen in Fig. 3(a)-3(b), for the positive impurity potential the resonance peak at the NN site of the impurity decreases with decreasing potential strength. At the impurity potential $V_s = 1$eV, the resonance peak almost disappears and merges into the SC coherence peak. However, the situation is quite different in the case of the negative impurity potential. At strong impurity potential $V_s = -10$eV, there is also a sharp resonance peak at the NN site of the impurity located at $\omega_0 = 6$meV, which is shifted to lower energy compared with that of the impurity potential $V_s = 10$eV. With decreasing the impurity potential, as shown in Fig. 3(d), the resonance peak at the NN site of the impurity splits into two peaks located at $\omega_0 = \pm 4.5$meV, and the peak at the negative energy is much stronger than that at the positive energy. At impurity potential $V_s = -1$eV, there

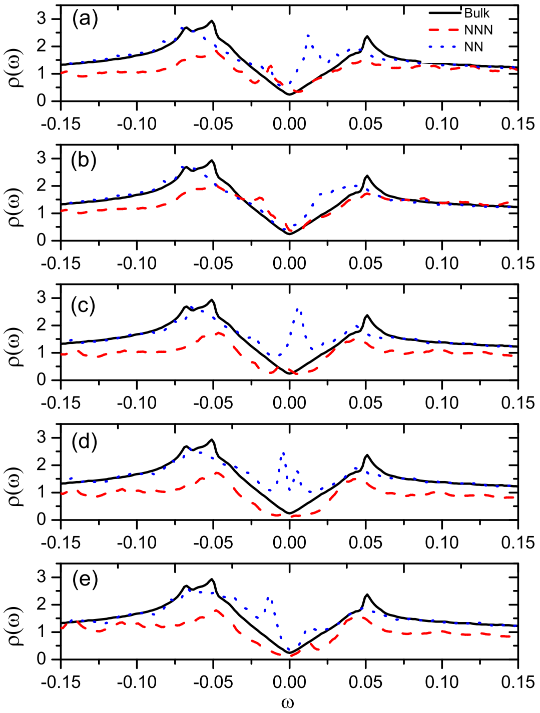

FIG. 3: (Color online) LDOS spectra around a nonmagnetic impurity at various potential strength for d-wave paring state. (a): $V_s = 3$eV; (b): $V_s = 1$eV; (c): $V_s = -10$eV; (d): $V_s = -2$eV; (e):$V_s = -1$eV.

are also two in-gap peaks at the NN site of the impurity located at $\omega_0 = \pm 13.5$meV, and the peak at the positive energy almost disappears.

The potential strength response of the impurity states for the p-wave paring state is presented in Fig. 4(a)-4(c). For the positive impurity strength, the LDOS spectra are similar to that of $V_s = 10$eV, i.e., two in-gap peaks occurring at the NNN site of the impurity. These results are not presented for simplicity. Here, we focus on the LDOS spectra of the negative impurity potential for the p-wave paring state. As can be seen, at the NN site of the impurity, the LDOS spectra are almost featureless compared with those in the bulk. However, there is an in-gap peak in the LDOS spectra at the NNN site of the impurity, and the SC coherence peaks are almost flattened. Moreover, the location of the in-gap peak shifts from $\omega_0 = 1.5$meV at $V_s = -10$eV to $\omega_0 = -4.5$meV at $V_s = -1.5$eV.

In summary, the impurity effects are studied for the BiS$_2$- layered superconductors based on a two orbital model with the BdG technique. From the calculation of multiple- impurity effect, significant reduction of T$_c$ is found for spin singlet NN paring d-wave state and spin triplet NNN paring p-wave state, while no depression of T$_c$ for isotropic s-wave state. The single- impurity effects for various paring states are also calculated. The impurity resonance peak in the LDOS spectrum is found only for the d-wave state. For the spin triplet NNN paring p-wave state, two in-gap peaks occur in the case of positive impurity potential; while a single in-gap peak is found for the negative impurity potential, which shifts towards to lower energy with decreasing the potential strength. These results can be used to detect the paring symmetry of the BiS$_2$- based superconductors.

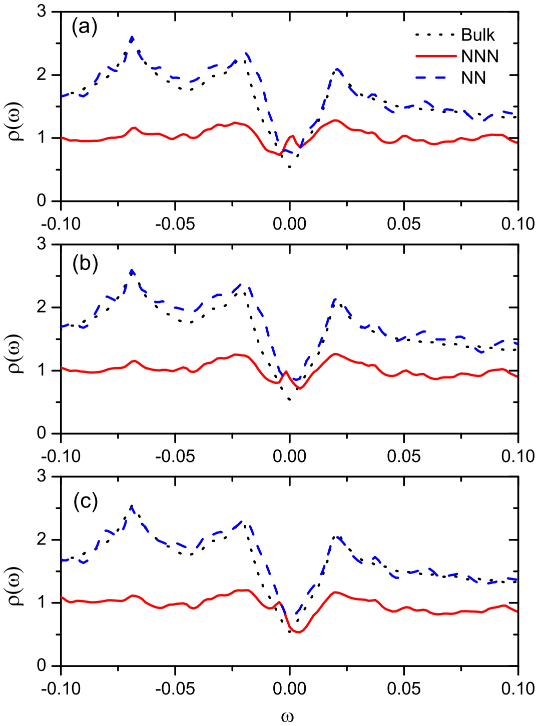

FIG. 4: (Color online) LDOS spectra around a nonmagnetic impurity at various potential strength for p-wave paring state. (a): $V_s = -10$eV; (b): $V_s = -3$eV; (c): $V_s = -1.5$eV.

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